



JL8205A

## N-Channel Enhancement Mode Power MOSFET

**Description**

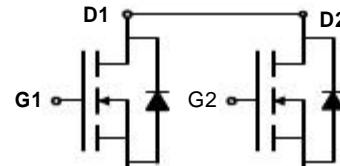
The JL8205A uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.

**General Features**

- $V_{DS} = 20V$ ,  $I_D = 6A$
- $R_{DS(ON)} < 34m\Omega$  @  $V_{GS}=2.5V$
- $R_{DS(ON)} < 24m\Omega$  @  $V_{GS}=4.5V$
- High Power and current handing capability
- Lead free product is acquired
- Surface Mount Package

**Application**

- Battery protection
- Load switch
- Power management



Schematic diagram



Marking and pin Assignment



TSSOP-8 top view

**Package Marking And Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
8205A	JL8205A	TSSOP-8	Ø330mm	12mm	3000 units

**Absolute Maximum Ratings (TA=25°C unless otherwise noted)**

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	$V_{DS}$	20	V
Gate-Source Voltage	$V_{GS}$	$\pm 10$	V
Drain Current-Continuous	$I_D$	6	A
Drain Current-Pulsed (Note 1)	$I_{DM}$	25	A
Maximum Power Dissipation	$P_D$	1.5	W
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55 To 150	°C

**Thermal Characteristic**

°C/W

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{eJA}$	83	
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**Electrical Characteristics (TA=25°C unless otherwise noted)**

Parameter	Symbol	Condition	Min	Typ	Max	Unit
<b>Off Characteristics</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V I_D=250\mu A$	20	21	-	V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=19.5V, V_{GS}=0V$	-	-	1	$\mu A$



深圳市矽源特科技有限公司

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Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±10V, V <sub>DS</sub> =0V	-	-	±100	nA
<b>On Characteristics (Note 3)</b>						
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	0.5	0.7	1.2	V
Drain-Source On-State Resistance	R <sub>DSON</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =4.5A	-	20	24	mΩ
		V <sub>GS</sub> =2.5V, I <sub>D</sub> =3.5A	-	25	34	mΩ
Forward Transconductance	g <sub>F</sub>	V <sub>DS</sub> =5V, I <sub>D</sub> =4.5A	-	10	-	S
<b>Dynamic Characteristics (Note4)</b>						
Input Capacitance	C <sub>ISS</sub>	V <sub>DS</sub> =8V, V <sub>GS</sub> =0V, F=1.0MHz	-	600	-	PF
Output Capacitance	C <sub>OSS</sub>		-	330	-	PF
Reverse Transfer Capacitance	C <sub>RSS</sub>		-	140	-	PF
<b>Switching Characteristics (Note 4)</b>						
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> =10V, I <sub>D</sub> =1A V <sub>GS</sub> =4.5V, R <sub>GEN</sub> =6Ω	-	10	20	nS
Turn-on Rise Time	t <sub>r</sub>		-	11	25	nS
Turn-Off Delay Time	t <sub>d(off)</sub>		-	35	70	nS
Turn-Off Fall Time	t <sub>f</sub>		-	30	60	nS
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> =10V, I <sub>D</sub> =6A, V <sub>GS</sub> =4.5V	-	10	15	nC
Gate-Source Charge	Q <sub>gs</sub>		-	2.3	-	nC
Gate-Drain Charge	Q <sub>gd</sub>		-	1.5	-	nC
<b>Drain-Source</b>						
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>s</sub> =1.7A	-	0.75	1.2	V
Diode Forward Current (Note 2)	I <sub>s</sub>		-	-	1.7	A



## TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

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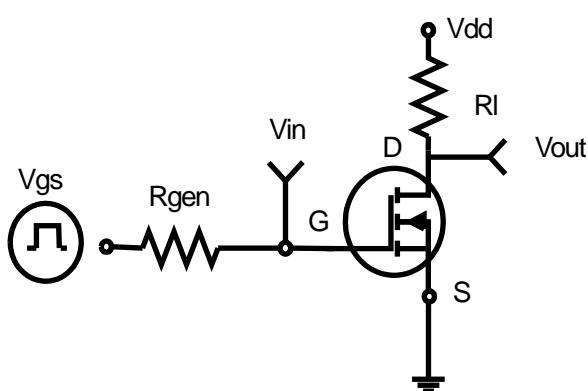


Figure 1:Switching Test Circuit

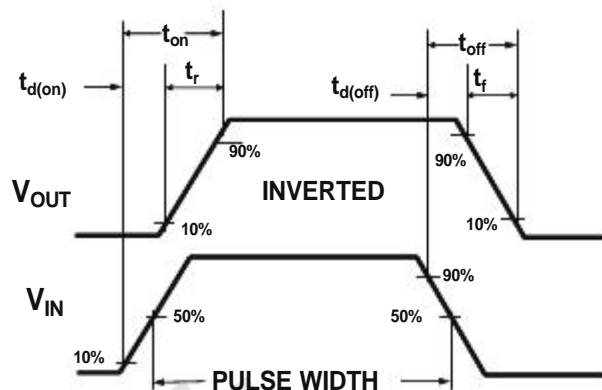


Figure 2:Switching Waveforms

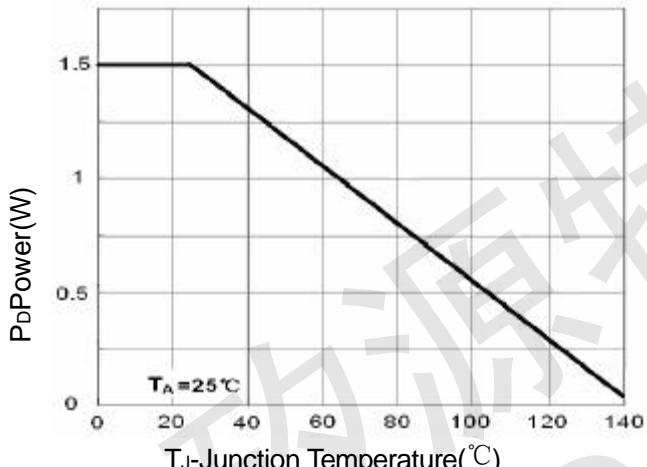


Figure 3 Power Dissipation

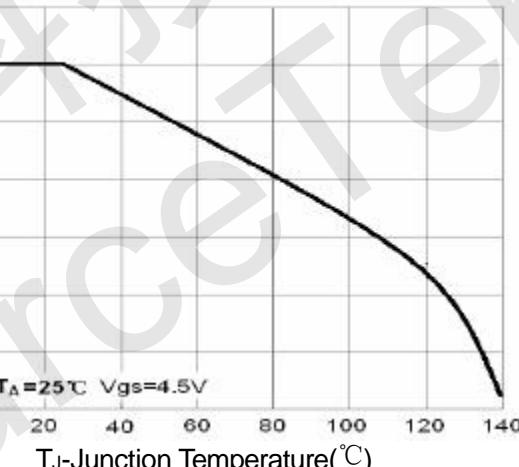


Figure 4 Drain Current

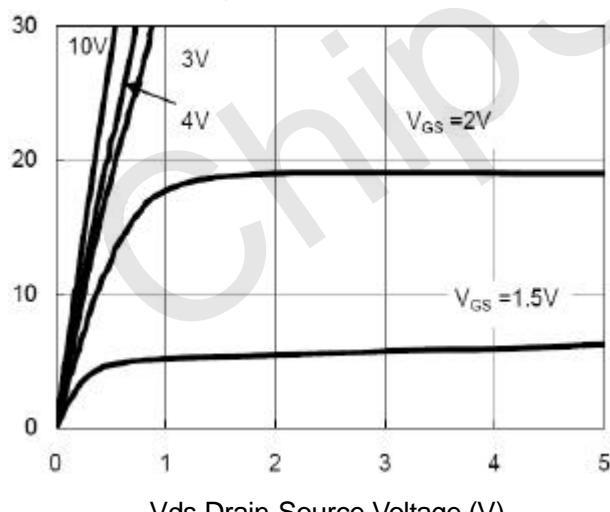


Figure 5 Output CHARACTERISTICS

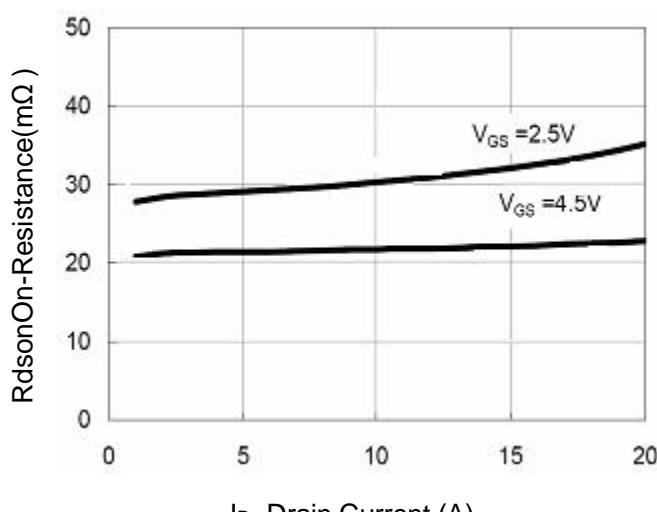


Figure 6 Drain-Source On-Resistance

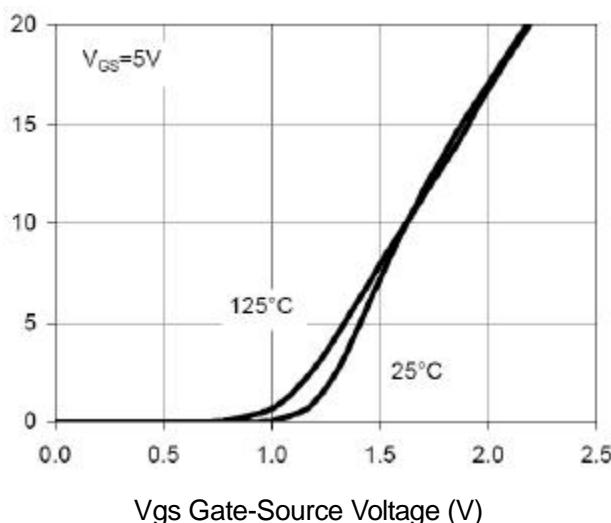


Figure 7 Transfer Characteristics

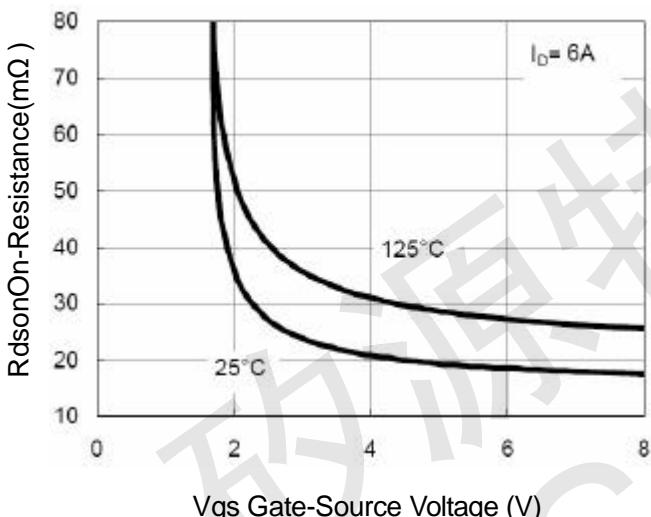
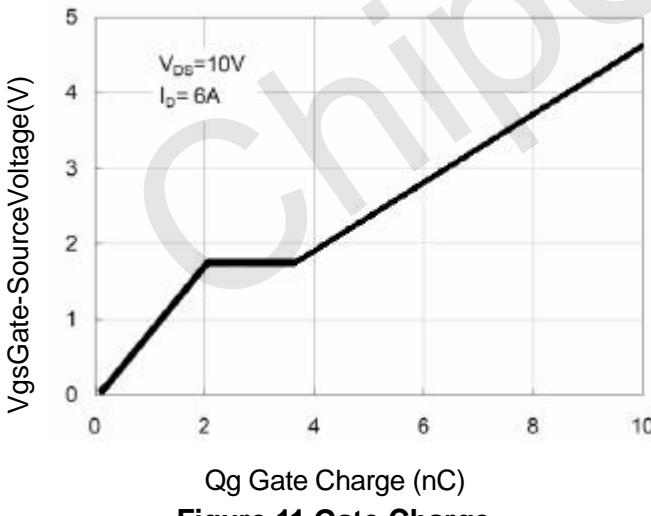
Figure 9  $R_{DS(on)}$  vs  $V_{GS}$ 

Figure 11 Gate Charge

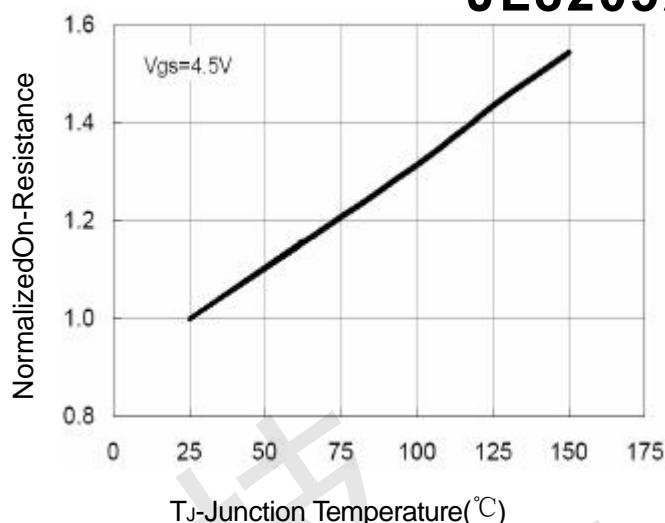


Figure 8 Drain-Source On-Resistance

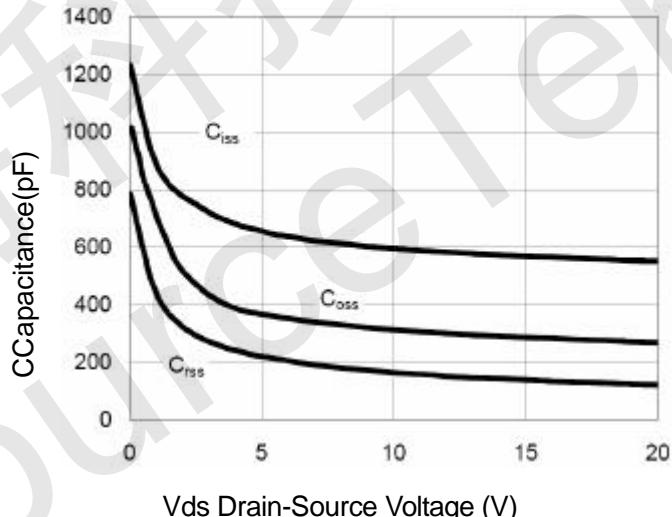
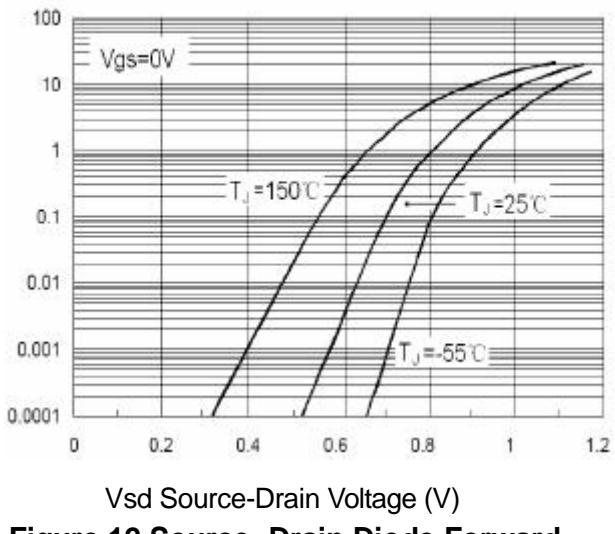
Figure 10 Capacitance vs  $V_{DS}$ 

Figure 12 Source-Drain Diode Forward



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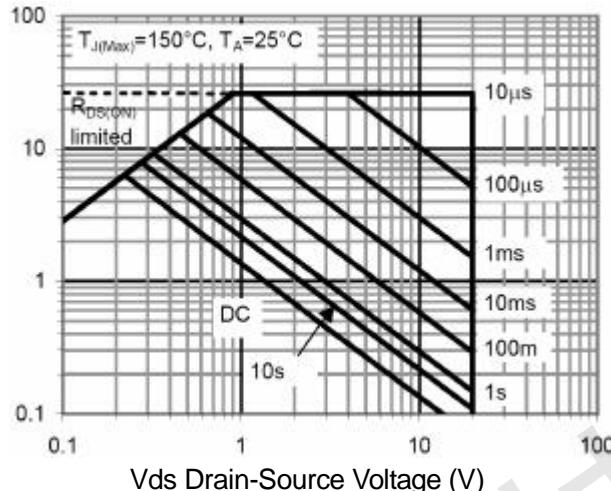


Figure 13 Safe Operation Area

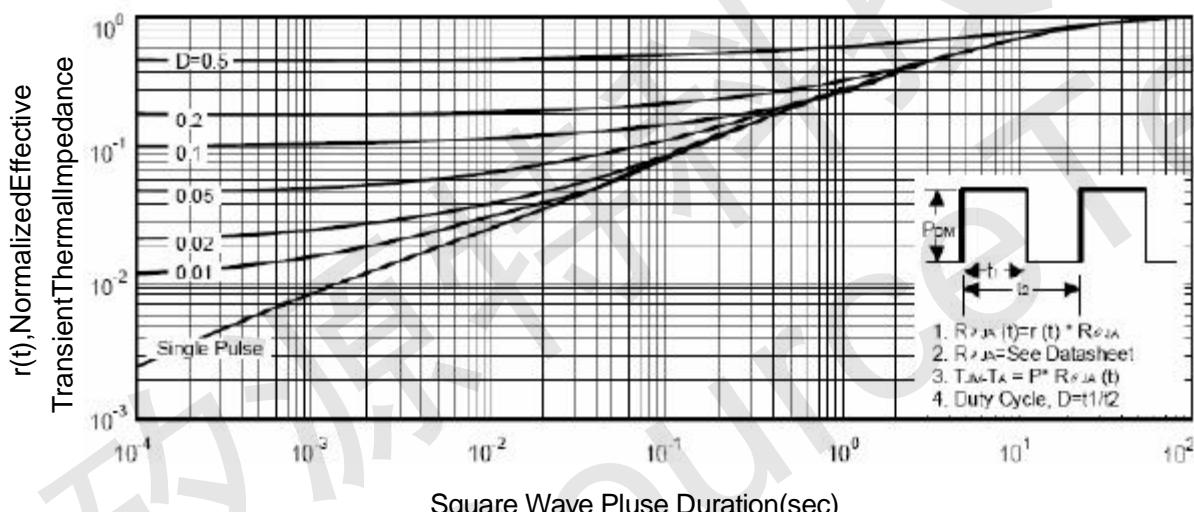
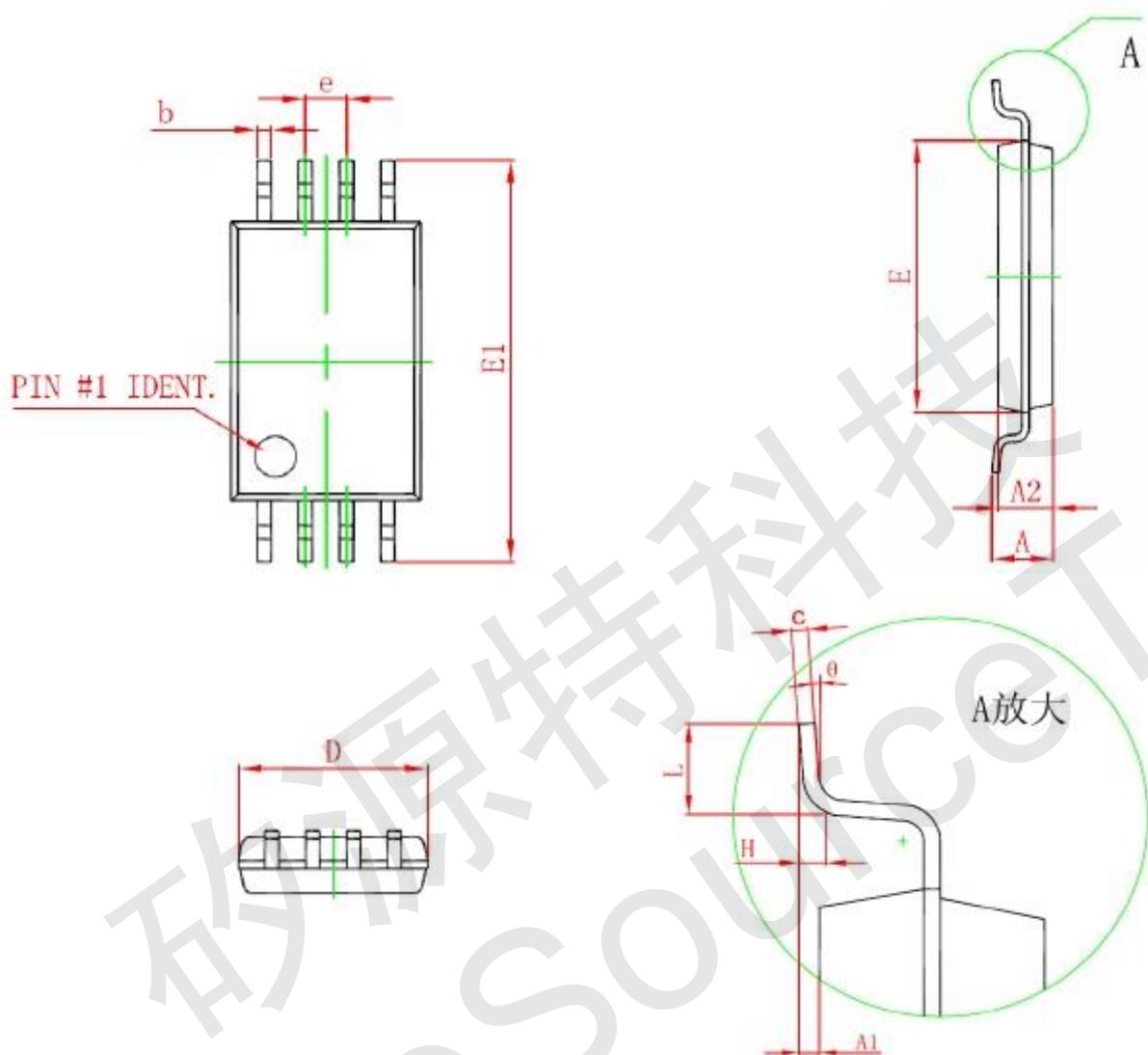


Figure 14 Normalized Maximum Transient Thermal Impedance



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## TSSOP-8 PACKAGE INFORMATION



Symbol	Dimensions In Millimeters	
	Min	Max
<b>D</b>	2.900	3.100
<b>E</b>	4.300	4.500
<b>b</b>	0.190	0.300
<b>c</b>	0.090	0.200
<b>E1</b>	6.250	6.550
<b>A</b>		1.100
<b>A2</b>	0.800	1.000
<b>A1</b>	0.020	0.150
<b>e</b>	0.65(BSC)	
<b>L</b>	0.500	0.700
<b>H</b>	0.25(TYP)	
<b><math>\Theta</math></b>	1°	7°